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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10008389	FILING DATE 11/06/2001	CLASS 438	SUBCLASS 12	GAU 2812	EXAMINER
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**CONTINUING DATA VERIFIED: *11/06/01*

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** FOREIGN APPLICATIONS VERIFIED:
JAPAN 2000-338708 11/07/2000 *yes*

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>
Foreign priority claimed 35 USC 119 conditions met		<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no
Verified and Acknowledged Examiner's initials		
TITLE : Bottom gate-type thin-film transistor and method for manufacturing the same		

U.S. DEPT. OF COMM/PAT & TM-PTO-146L (Rev. 10-94)

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED	
			Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING		
Amount Due	Date Paid	Sheets Drwg.	Fig. Drwg.	Print Fig.
TERMINAL DISCLAIMER		Primary Examiner		
		Prepared for Issue		
		Application Examiner		
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